

Vishay General Semiconductor

Surface Mount Glass Passivated Junction Fast Switching Rectifier

Major Ratings and Characteristics

I _{F(AV)}	1.0 A
V _{RRM}	50 V to 1000 V
I _{FSM}	30 A
t _{rr}	150 ns, 250 ns, 500 ns
V _F	1.3 V
T _j max.	175 °C



Patented[®] *Glass-plastic encapsulation is covered by Patent No. 3,996,602, brazed-lead assembly to Patent No. 3,930,306

DO-213AB

Features

- · Superectifier structure for high reliability condition
- Patented glass-plastic encapsulation technique
- Ideal for automated placement
- · Fast switching for high efficiency
- Low leakage current
- · High forward surge capability
- Meets environmental standard MIL-S-19500
- Meets MSL level 1, per J-STD-020C
- Solder Dip 260 °C, 40 seconds

Mechanical Data

Case: DO-213AB, molded epoxy over glass body Epoxy meets UL-94V-0 Flammability rating

Terminals: Matte tin plated leads, solderable per

J-STD-002B and JESD22-B102D

E3 suffix for commercial grade, HE3 suffix for high reliability grade (AEC Q101 qualified)

Polarity: Two bands indicate cathode end - 1st band denotes device type and 2nd band denotes repetitive peak reverse voltage rating

Typical Applications

For use in fast switching rectification of power supply, inverters, converters, and freewheeling diodes for consumer, automotive and Telecommunication

Maximum Ratings

(T_A = 25 °C unless otherwise noted)

Parameter	Symbols	BYM	BYM	BYM	BYM	BYM	BYM	BYM	Units
		11-50	11-100	11-200	11-400	11-600	11-800	11-1000	
Fast switching time device: 1st band is Red		RGL	RGL	RGL	RGL	RGL	RGL	RGL	
		41A	41B	41D	41G	41J	41K	41M	
Polarity color bands (2nd Band)		Gray	Red	Orange	Yellow	Green	Blue	Violet	
Maximum repetitive peak reverse voltage	V_{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS voltage	V _{RMS}	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	V_{DC}	50	100	200	400	600	800	1000	V
Maximum average forward rectified current at $T_T = 55~^{\circ}C$	I _{F(AV)}	1.0							
Peak forward surge current 8.3 ms single half sinewave superimposed on rated load	I _{FSM}	30							Α
Maximum full load reverse current, full cycle average at $T_A = 55 ^{\circ}\text{C}$	I _{R(AV)}	50							μΑ
Operating junction and storage temperature range	T_J, T_{STG}	- 65 to + 175							°C

Document Number 88547 www.vishay.com

22-Sep-05

BYM11-50 thru BYM11-1000, RGL41A thru RGL41M

Vishay General Semiconductor



Electrical Characteristics

(T_A = 25 °C unless otherwise noted)

Parameter	Test condition	Symbols	BYM 11-50	BYM 11-100	BYM 11-200	BYM 11-400	BYM 11-600	BYM 11-800	BYM 11-1000	Units
Maximum instantaneous forward voltage	at 1.0 A	V _F		1.3						V
Maximum DC reverse current at rated DC blocking voltage	T _A = 25 °C T _A = 125 °C	I _R	5.0 50							μΑ
Maximum reverse recovery time	at $I_F = 0.5 \text{ A}$, $I_R = 1.0 \text{ A}$, $I_{rr} = 0.25 \text{ A}$	t _{rr}	150 250 500				00	ns		
Typical junction capacitance	at 4.0 V, 1 MHz	CJ	15					pF		

Thermal Characteristics

(T_A = 25 °C unless otherwise noted)

Parameter	Symbols	BYM	BYM	BYM	BYM	BYM	BYM	BYM	Units
		11-50	11-100	11-200	11-400	11-600	11-800	11-1000	
Maximum thermal resistance	$R_{\theta JA}$	75 ⁽¹⁾						°C/W	
	$R_{\theta JT}$	30 ⁽²⁾							

Notes:

- (1) Thermal resistance from junction to ambient, 0.24 x 0.24" (6.0 x 6.0 mm) copper pads to each terminal
- (2) Thermal resistance from junction to terminal, 0.24 x 0.24" (6.0 x 6.0 mm) copper pads to each terminal

Ratings and Characteristics Curves

(T_A = 25 °C unless otherwise noted)

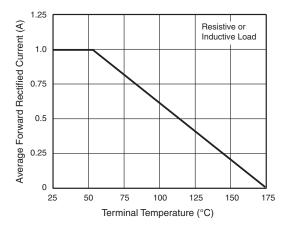


Figure 1. Forward Current Derating Curve

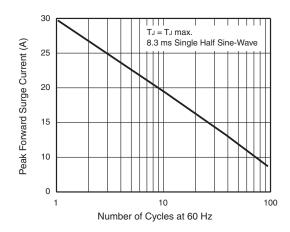


Figure 2. Maximum Non-Repetitive Peak Forward Surge Current



Vishay General Semiconductor

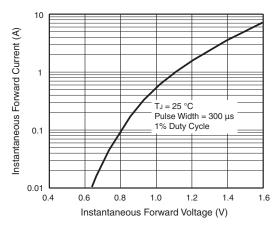


Figure 3. Typical Instantaneous Forward Characteristics

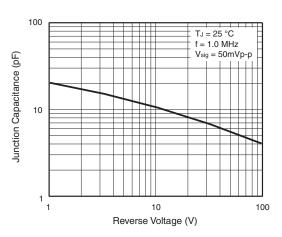


Figure 5. Typical Junction Capacitance

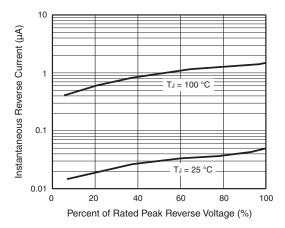


Figure 4. Typical Reverse Characteristics

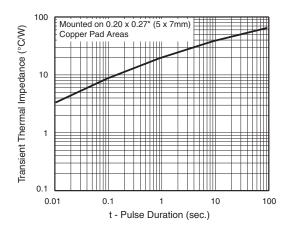
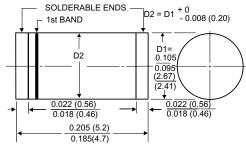


Figure 6. Typical Transient Thermal Impedance

Package outline dimensions in inches (millimeters)

DO-213AB



1st band denotes type and positive end (cathode)

Legal Disclaimer Notice



Vishay

Notice

Specifications of the products displayed herein are subject to change without notice. Vishay Intertechnology, Inc., or anyone on its behalf, assumes no responsibility or liability for any errors or inaccuracies.

Information contained herein is intended to provide a product description only. No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document. Except as provided in Vishay's terms and conditions of sale for such products, Vishay assumes no liability whatsoever, and disclaims any express or implied warranty, relating to sale and/or use of Vishay products including liability or warranties relating to fitness for a particular purpose, merchantability, or infringement of any patent, copyright, or other intellectual property right.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications. Customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Vishay for any damages resulting from such improper use or sale.

www.vishay.com Revision: 08-Apr-05